



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|--------------------------------|--|
| 20V | 0.99Ω @ $V_{GS} = 4.5V$ | 450mA |
| | 1.2Ω @ V _{GS} = 2.5V | 400mA |
| | 1.8Ω @ V _{GS} = 1.8V | 330mA |
| | 2.4Ω @ V _{GS} = 1.5V | 300mA |

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 1mm x 1mm
- Low Package Profile, 0.45mm Maximum Package Height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

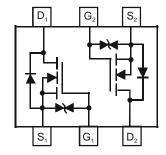
- Case: SOT963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.027 grams (Approximate)





SOT963

Top View



Top View Schematic and Transistor Diagram

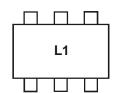
Ordering Information (Note 5)

| Part Number | Case | Packaging |
|---------------|--------|-----------------|
| DMN2990UDJQ-7 | SOT963 | 10K/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



L1 = Product Type Marking Code

DMN2990UDJQ Document number: DS39441 Rev. 1 - 2 1 of 7

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|--|-----------------|--|------------------|------------|------|
| Drain-Source Voltage | | | V_{DSS} | 20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±8 | V |
| Continuous Drain Current (Note 6) V _{GS} = 4.5V | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | 450 350 | mA |
| Continuous Drain Current (Note 6) V _{GS} = 1.8V | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | 330 220 | mA |
| Pulsed Drain Current (Note 7) | | | I _{DM} | 800 | mA |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 6) | P _D | 350 | mW |
| Thermal Resistance, Junction to Ambient | $R_{	hetaJA}$ | 360 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

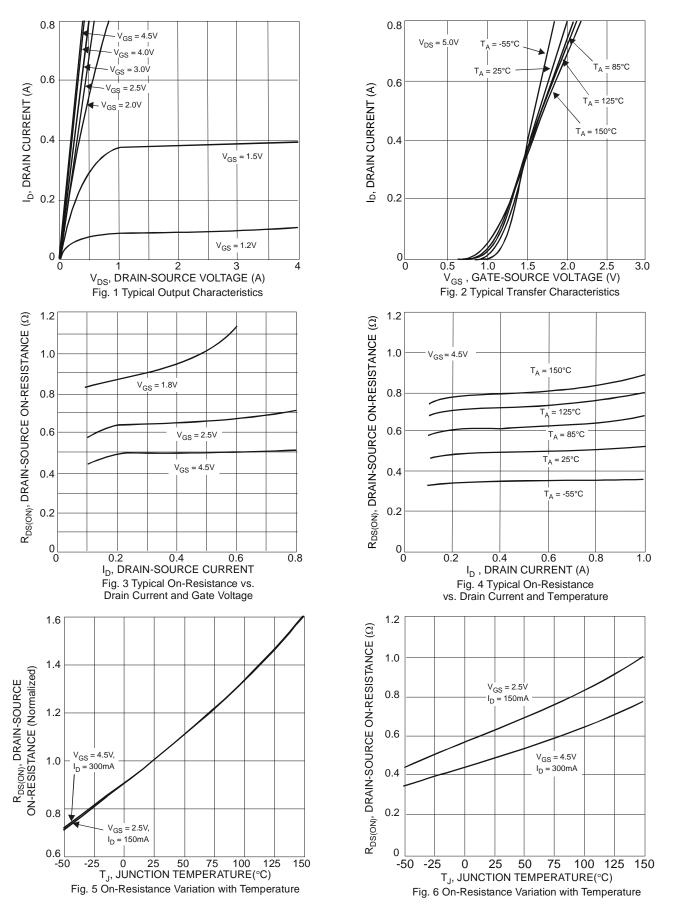
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Observatoriation | 0 | N4: | T | N/I | 1111 | To al Oo andidan | |
|---|---------------------|-----|------|------|----------|---|--|
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
| OFF CHARACTERISTICS (Note 8) | | | ı | 1 | | T., | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | - | - | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current @T _C = +25°C | I _{DSS} | • | - | 50 | nA | $V_{DS} = 5V$, $V_{GS} = 0V$ | |
| Zero Gate Voltage Brain Gunerit & 10 = 125 G | | - | - | 100 | | $V_{DS} = 16V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I_{GSS} | - | - | ±100 | nA | $V_{GS} = \pm 5V$, $V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | 0.4 | - | 1.0 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | |
| | | - | 0.60 | 0.99 | | $V_{GS} = 4.5V, I_D = 100mA$ | |
| | | - | 0.75 | 1.2 | | $V_{GS} = 2.5V, I_D = 50mA$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | - | 0.90 | 1.8 | Ω | $V_{GS} = 1.8V, I_D = 20mA$ | |
| | 25(5.1) | - | 1.2 | 2.4 | | $V_{GS} = 1.5V, I_D = 10mA$ | |
| | | - | 2.0 | - | | $V_{GS} = 1.2V, I_D = 1mA$ | |
| Forward Transfer Admittance | Y _{fs} | 180 | - | - | ms | V _{DS} = 10V, I _D = 400mA | |
| Diode Forward Voltage (Note 7) | V _{SD} | - | 0.6 | 1.0 | V | $V_{GS} = 0V, I_{S} = 150mA$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | Ciss | - | 27.6 | - | pF | .,, | |
| Output Capacitance | Coss | - | 4.0 | - | pF | $V_{DS} = 16V, V_{GS} = 0V,$ - f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | - | 2.8 | - | pF | 71 = 1.0MH2 | |
| Total Gate Charge | Qq | - | 0.5 | - | nC | V _{GS} = 4.5V, V _{DS} = 10V, I _D = 250mA | |
| Gate-Source Charge | Q _{gs} | - | 0.07 | - | nC | | |
| Gate-Drain Charge | Q_{gd} | - | 0.07 | - | nC | | |
| Turn-On Delay Time | t _{D(ON)} | - | 4.0 | - | ns | | |
| Turn-On Rise Time | t _R | - | 3.3 | - | ns | $V_{DD} = 10V, V_{GS} = 4.5V,$ $R_{L} = 47\Omega, R_{g} = 10\Omega,$ $I_{D} = 200\text{mA}$ | |
| Turn-Off Delay Time | t _{D(OFF)} | - | 19.0 | - | ns | | |
| Turn-Off Fall Time | t _F | - | 6.4 | - | ns | | |

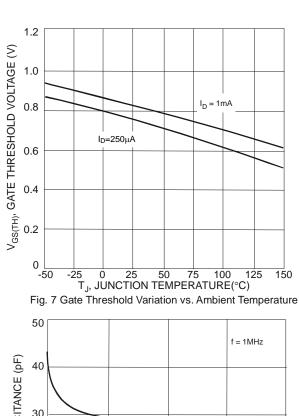
Notes: 6. Device mounted on FR-4 PCB, with minimum recommended pad layout.

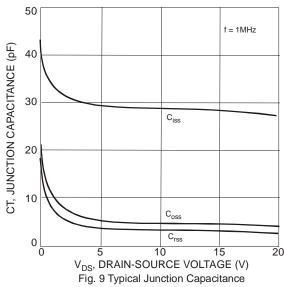
- 7. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.

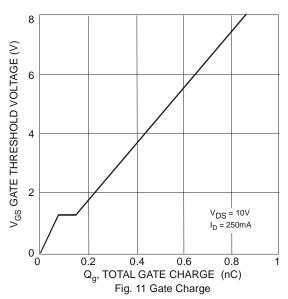


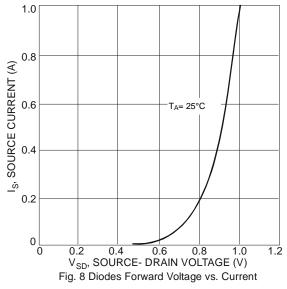












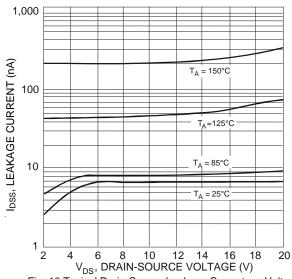
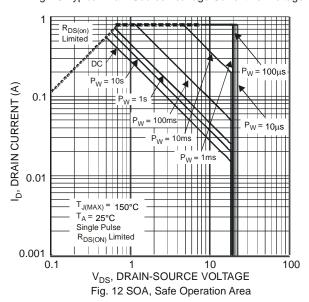


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage





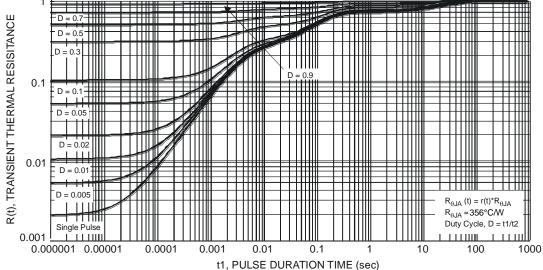


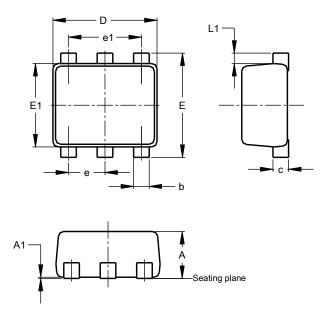
Fig. 13 Transient Thermal Resisitance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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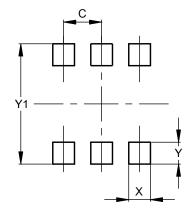


| SOT963 | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.40 | 0.50 | 0.45 | | |
| A1 | 0.00 | 0.05 | | | |
| b | 0.10 | 0.20 | 0.15 | | |
| С | 0.120 | 0.180 | 0.150 | | |
| ם | 0.95 | 1.05 | 1.00 | | |
| Е | 0.95 | 1.05 | 1.00 | | |
| E1 | 0.75 | 0.85 | 0.80 | | |
| е | | | 0.35 | | |
| e1 | | | 0.70 | | |
| L1 | 0.05 | 0.15 | 0.10 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

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| Dimensions | Value (in mm) | | |
|------------|------------------|--|--|
| С | 0.350 | | |
| Х | 0.200 | | |
| Y | 0.200 | | |
| Y1 | 1.100 | | |



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